ESE 562_Project 3

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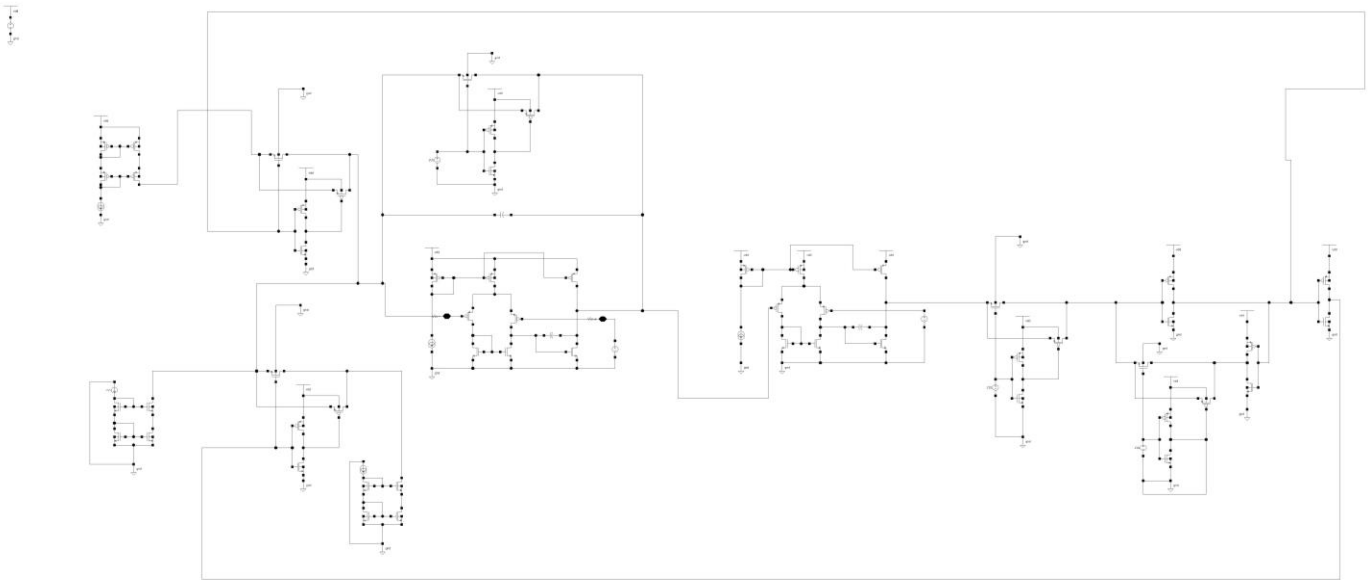
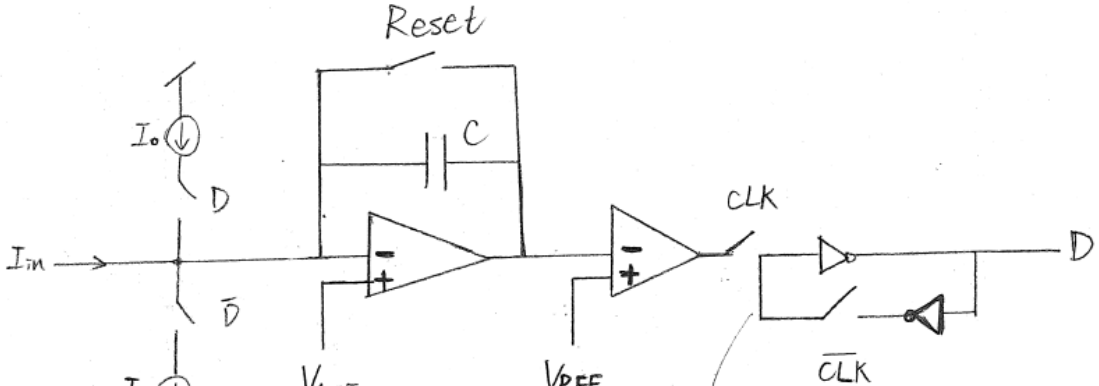
System level architecture with component values (C, Io, CLK, VREF, VCMP)

Vdd – Vdc(3V) – gnd



C =11.5 p

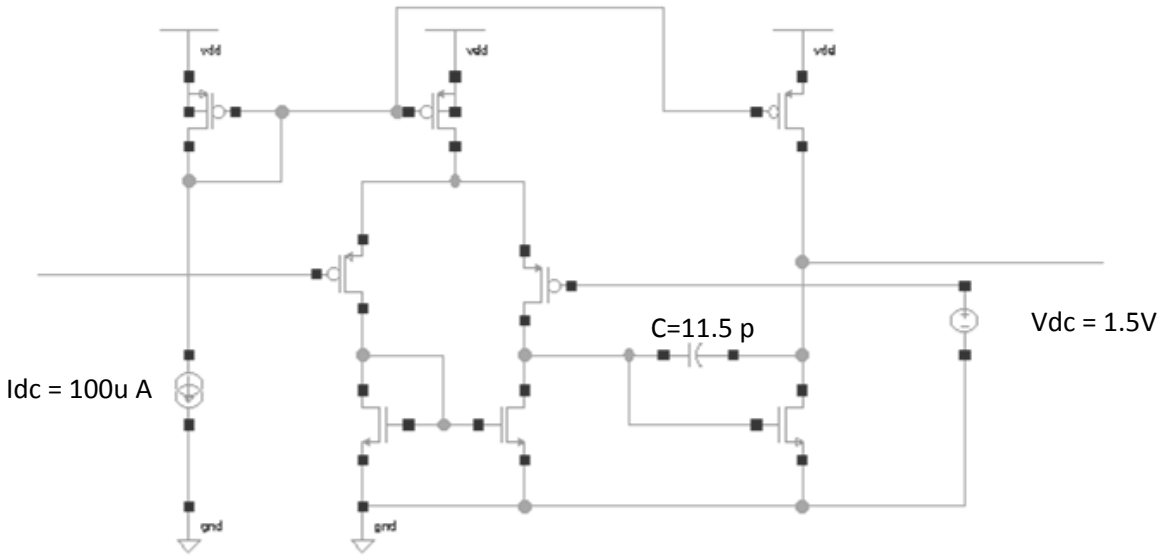


C	Io	CLK	V_{ref}	V_{CMP}
3p	130n A	V pulse 0 ~ 3V (3~0V)	1.5 V	1.5 V
		Pulse width 20u s		
		Period 40u s		

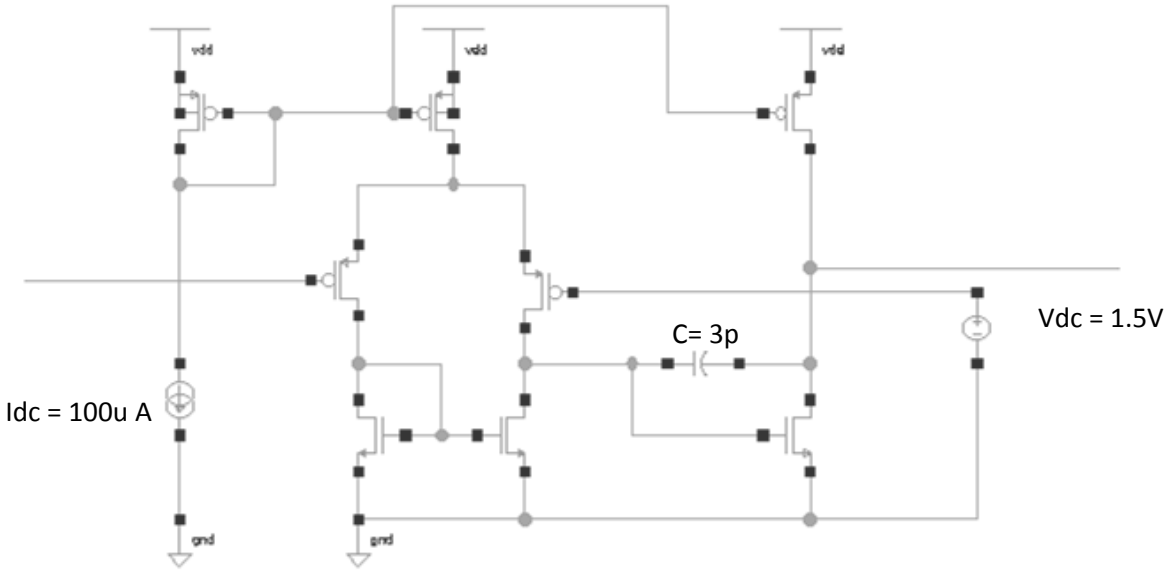
Amplifier Implementation

I chose the amplifier as the one in project 1.

1.

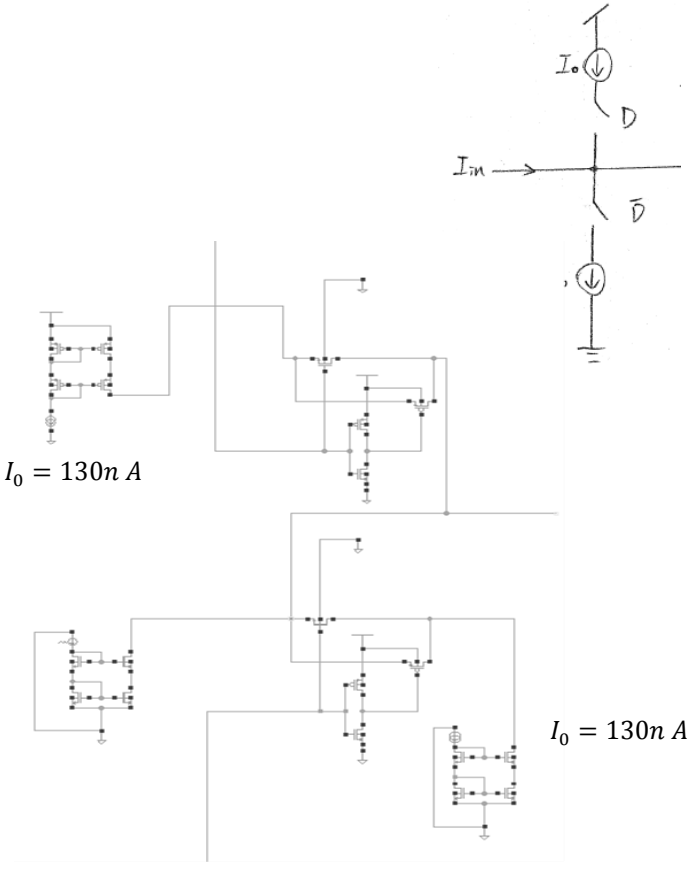


2.

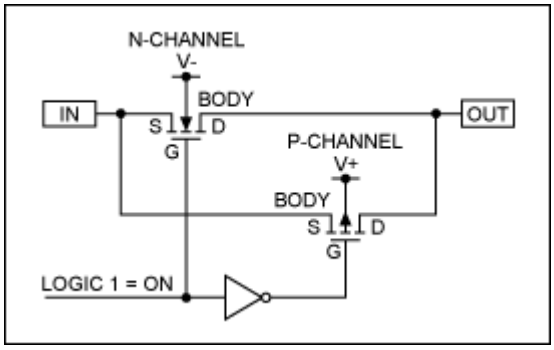


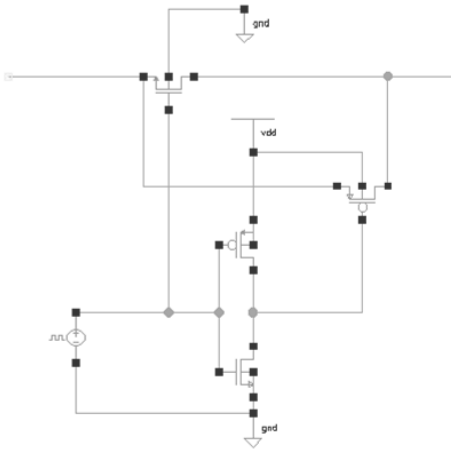
Implementation

Current Source and Sink

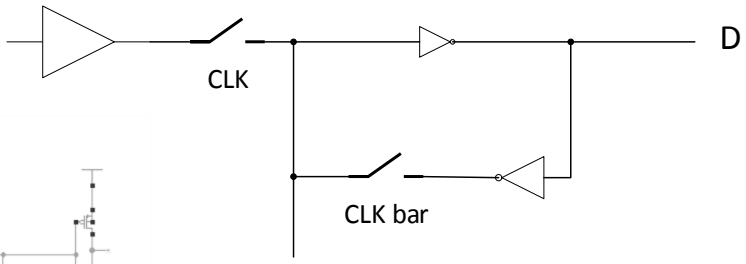


CMOS Switch

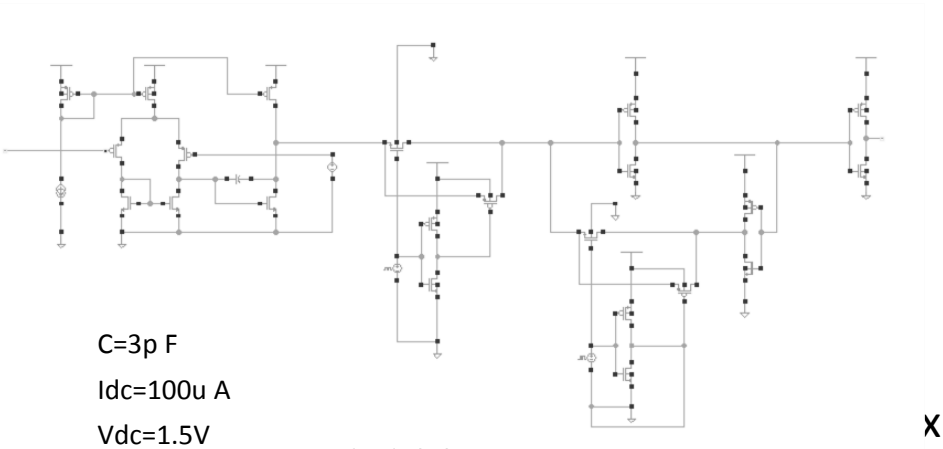




Latched Comparator



D bar



C=3p F

Idc=100u A

Vdc=1.5V

CLK is 0~3V

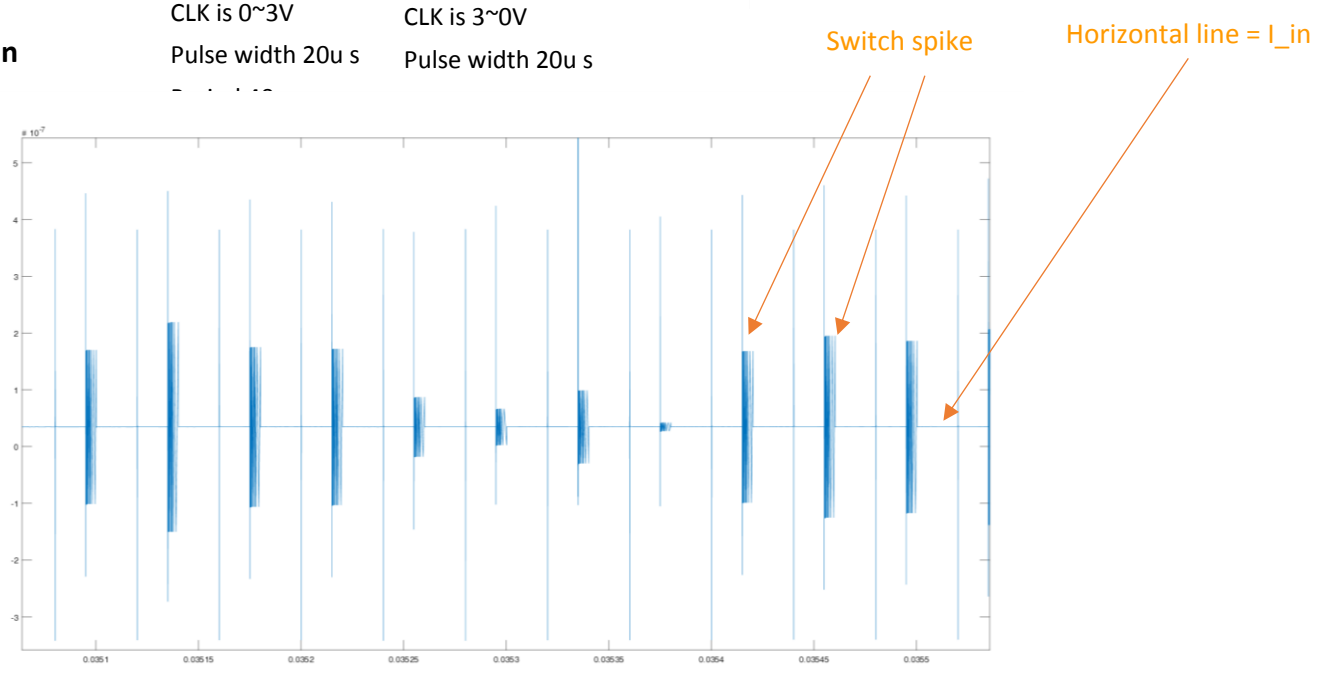
Pulse width 20u s

CLK is 3~0V

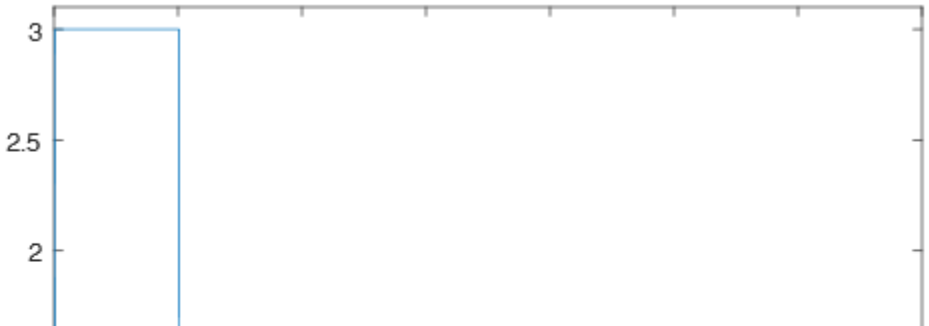
Pulse width 20u s

X

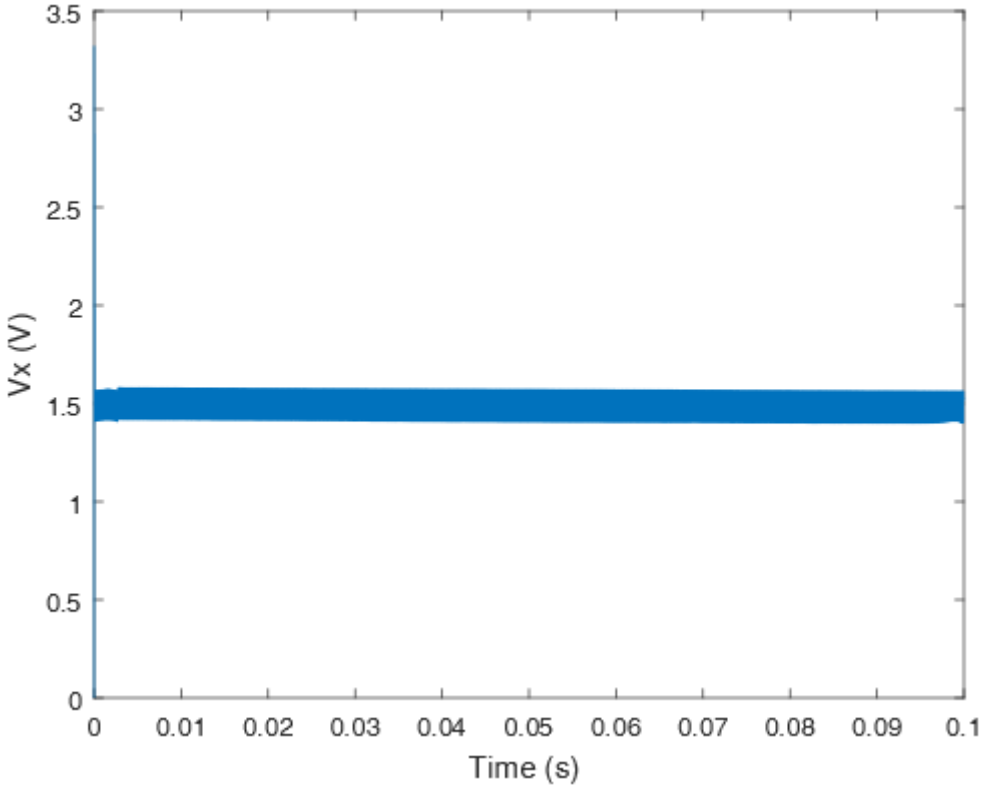
Iin



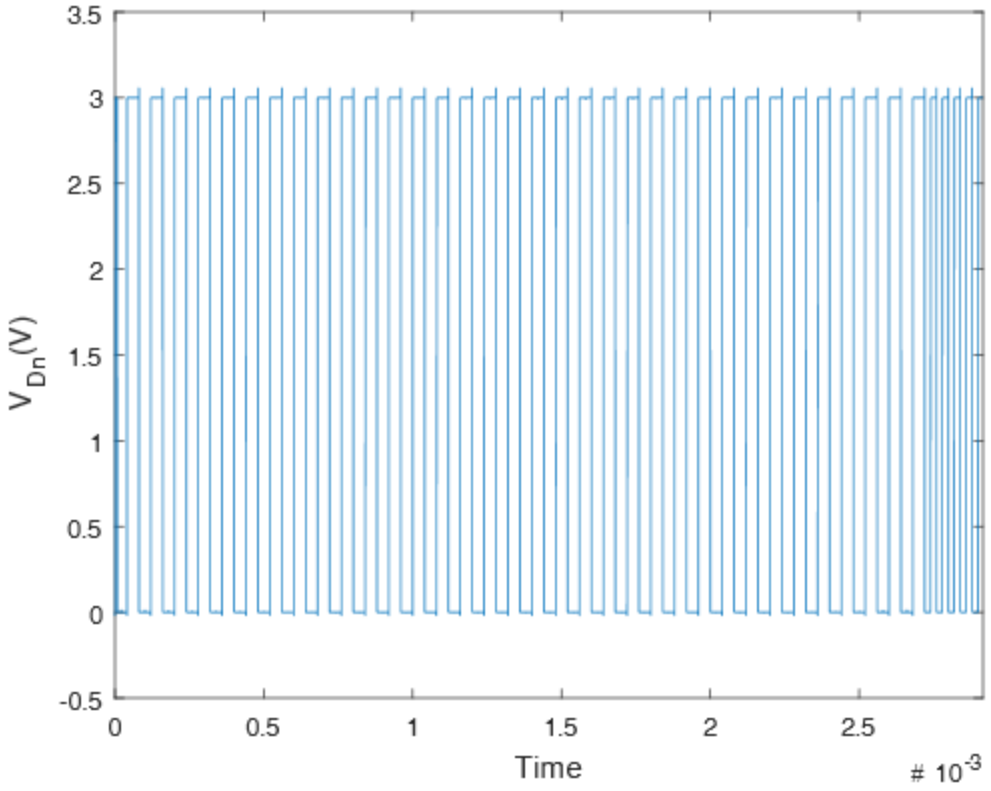
V_reset:

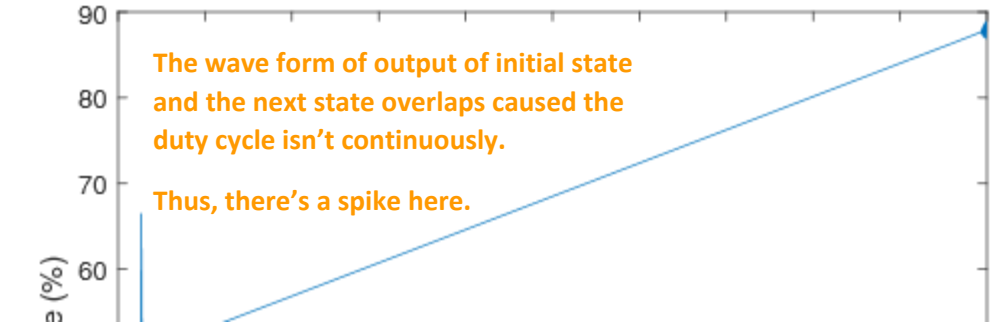


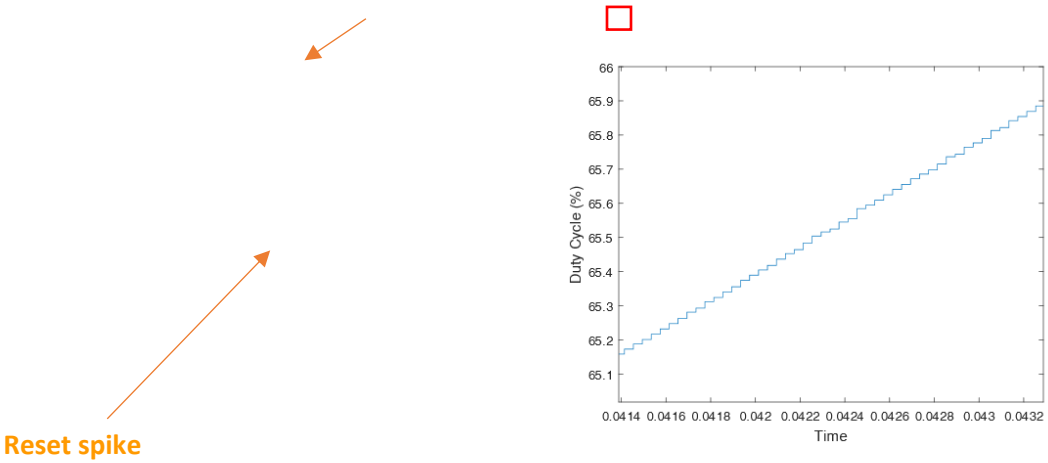
Vx


3.5
3
2.5
2
1.5
1
0.5
0
Vx (V)
0
0.01
0.02
0.03
0.04
0.05
0.06
0.07
0.08
0.09
0.1
Time (s)

V_Dn and Duty Cycle







Speed:

CLK is 0~3V and 3~0V

Pulse width 20u s

Period 40u s

Resolution:

Since there are 2410 data points in duty cycle.

$log_2 2410 = 11.2348174$

=>The resolution is 11.2 bit.

Power Dissipation:

P = I*V

P = 399u A* 3 V = 1.2m Watt